MA4AGP907 MA4AGFCP910



AlGaAs Flip Chip PIN Diodes

Rev. V5

Features

- Low Series Resistance
- Ultra Low Capacitance
- Millimeter Wave Switching & Cutoff Frequency
- 2 Nanosecond Switching Speed
- ♦ Can be Driven by a Buffered TTL
- Silicon Nitride Passivation
- Polyimide Scratch Protection
- RoHS Compliant

Description

M/A-COM's MA4AGP907 and MA4AGFCP910 are Aluminum Gallium Arsenide (AlGaAs) flip-chip PIN diodes. These devices are fabricated on OMCVD epitaxial wafers using a process designed for high device uniformity and extremely low parasitics. The diodes exhibit an extremely low RC product, (0.1ps) and 2-3nS switching characteristics. They are fully passivated with silicon nitride and have an added polymer layer for scratch protection. The protective coating prevents damage to the junction and the anode air-bridge during handling and assembly.

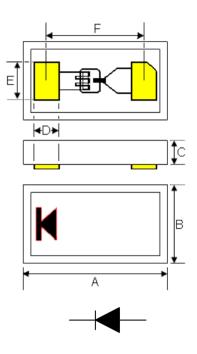
Applications

The ultra low capacitance of the MA4AGP907 and MA4AGFCP910 allows their use through millimeter frequencies for RF switches and switched phase shifter applications. The diodes are designed for use in pulsed or CW applications, where single digit nS switching speed is required. For surface mount assembly, the low capacitance of these switches make them ideal for use in microwave multi-throw switch assemblies, where the series capacitance of each "off" port adversely loads the input and affects VSWR.

Absolute Maximum Ratings T_{AMB} = +25°C (unless otherwise specified)

· · · · · · · · · · · · · · · · · · ·	· · · · · · · · · · · · · · · · · · ·			
Parameter	Absolute Maximum			
Doverse Veltage	MA4AGP907 -50V			
Reverse Voltage	MA4AGFCP910 -75V			
Operating Temperature	-55°C to +125°C			
Storage Temperature	-55°C to +150°C			
Junction Temperature	+175°C			
Dissipated Power (RF & DC)	50mW			
C.W. Incident Power	+23 dBm			
Mounting Temperature	+280°C for 10 seconds			
	1			

Chip Dimensions MA4AGP907 and MA4AGFCP910



Notes:

- 1. Gold Pads 14µM thick.
- 2. Yellow areas indicate ohmic gold mounting pads.
- 3. Dimensions A thru F are identical for both devices

	INCI	HES	MM		
DIM	MIN.	MAX.	MIN.	MAX.	
Α	0.026	0.027	0.6604	0.6858	
В	0.0135	0.0145	0.3429	0.3683	
С	0.0065	0.0075	0.1651	0.1905	
D	0.0043	0.0053	0.1092	0.1346	
E	0.0068	0.0073	0.1727	0.1854	
F	0.0182	0.0192	0.4623	0.4877	

1



Rev. V5

Electrical Specifications @ T_{AMB} = +25°C

Parameter	Symbol	Conditions	Units	MA4AGP907		MA4AGFCP910	
Farameter	Syllibol	onariono on	Units	Тур.	Max.	Тур.	Max.
Total Capacitance	Ст	MA4AGP907 -5V,1MHz	- pF	0.025	0.030	0.018	0.021
Total Capacitance	O ₁	MA4AGFCP910 -10V,1MHz	- pr	0.023	0.030	0.010	0.021
Total Capacitance ¹	C _T	-5V, 10GHz	pF	0.020		0.018	0.021
Series Resistance	Rs	+10mA, 1MHz	Ω	5.2	7.0		
Series Resistance ²	R _s	+10mA, 10GHz	Ω	4.2		5.2	6.0
Forward Voltage	V _F	+10mA	V	1.33	1.45	1.33	1.45
Reverse Leakage Current ³	I_R	MA4AGP907 V _R = -50V	μA		10		10
Neverse Leakage Current	I R	MA4AGFCP910 V _R = -75V	μΛ		10		10
Switching Speed ⁴	T _{RISE} T _{FALL}	10GHz	nS	2		2	
Carrier Lifetime	TL	I _F = 10mA / I _{REV} = 6mA	nS			4	

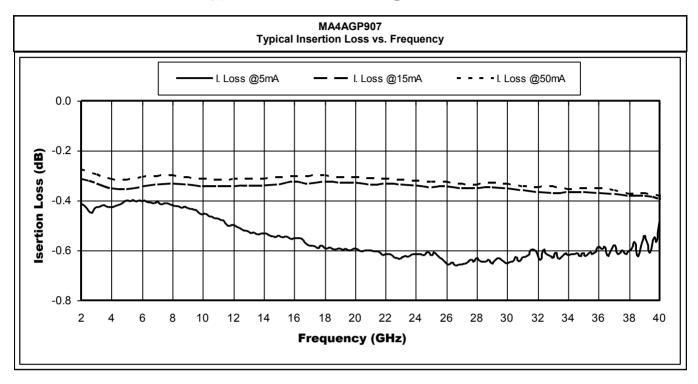
Notes:

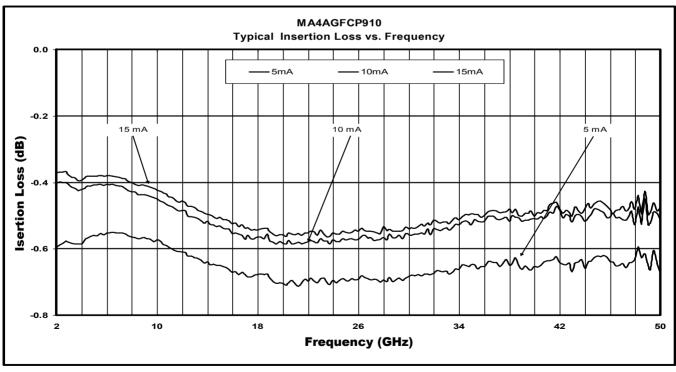
- 1) Capacitance is determined by measuring the isolation of a single series diode in a 50Ω transmission line at 10GHz.
- 2) Series resistance is determined by measuring the insertion loss of a single series diode in a 50Ω transmission line at 10GHz.
- 3) The max rated V_R (Reverse Voltage) is sourced and the resultant reverse leakage current, Ir, is measured to be <10 μA
- 4) Switching speed is measured between 10% and 90% or 90% to 10% RF voltage for a single series mounted diode. Driver delay is not included.



Rev. V5

Typical RF Performance @ T_{AMB} = +25°C

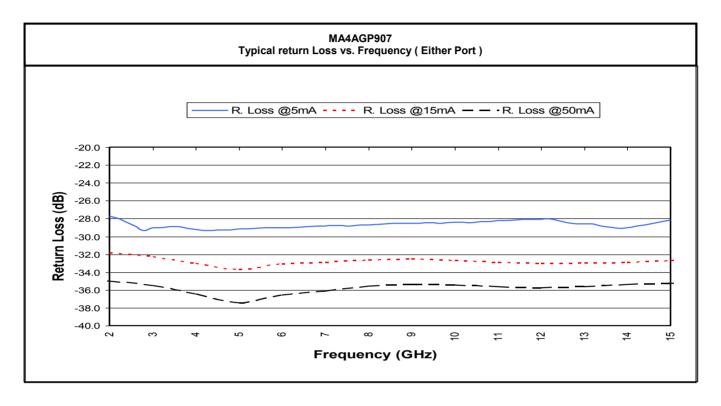


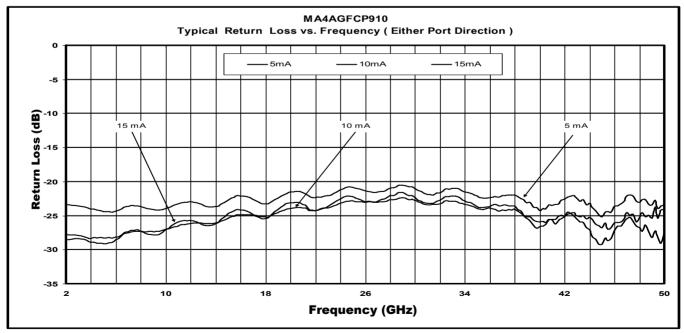




Rev. V5

Typical RF Performance @ T_{AMB} = +25°C



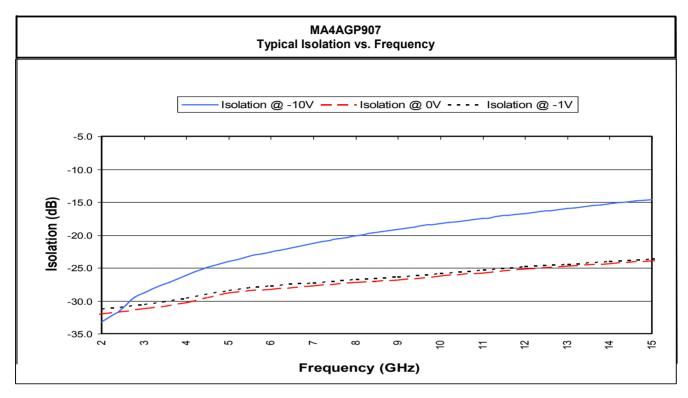


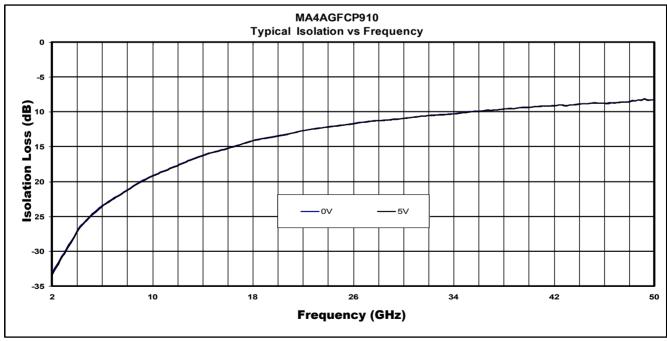
Frequency (Hz)



Rev. V5

Typical RF Performance @ T_{AMB} = +25°C





MA4AGP907 MA4AGFCP910



AlGaAs

Flip Chip PIN Diodes

Rev. V5

Device Installation Guidelines

Cleanliness

These devices should be handled in a clean environment. The chips are resistant to solvents and may cleaned using approved industry standard practices.

Static Sensitivity

Aluminum Gallium Arsenide PIN diodes are ESD sensitive and can be damaged by static electricity. Proper ESD techniques should be used when handling these devices. These devices are rated Class 0, (0-199V) per HBM MIL-STD-883, method 3015.7 [C = 100pF \pm 10%, R = 1.5kW \pm 1%]. Even though tested die pass 50V ESD, they must be handled in a static-free environment.

General Handling

The devices have a polymer layer which provides scratch protection for the junction area and the anode air bridge. Die can be handled with plastic tweezers or picked and placed with a #27 tip vacuum pencil.

Assembly Requirements using Electrically Conductive Silver Epoxy and Solder

These chips are designed to be inserted onto hard or soft substrates with the junction side down. They should be mounted onto silk-screened circuits using electrically conductive silver epoxy, approximately 1-2 mils in thickness and cured at approximately 90°C to 150°C per manufacturer's schedule. For extended cure times, > 30 minutes, temperatures must be below 200°C.

Eutectic Die Attached

Tin rich solders (>30% Sn by weight) are not recommended as they will scavenge the gold on the contact Pads exposing the tungsten metallization beneath and creating a poor solder connection. Indalloy or 80/20, Au/Sn type solders are acceptable. Maximum soldering temperature must be kept below 280°C for less than 10 seconds.

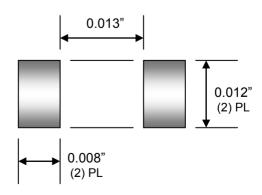
Note:

The MA4AGSBP907 which is a solder bumped version of the MA4AGP907, is also available. The datasheet can be viewed on the M/A-COM website at: http://www.macom.com/DataSheets/MA4AGSBP907.pdf

Ordering Information

Part Number	Packaging
MA4AGP907	Gel Pack
MADP-001907-13050P	Pocket Tape
Part Number	Packaging
Part Number MA4AGFCP910	Packaging Gel Pack

Circuit Pad Layout



MA4AGP907 MA4AGFCP910



AlGaAs Flip Chip PIN Diodes

Rev. V5

M/A-COM Technology Solutions Inc. All rights reserved.

Information in this document is provided in connection with M/A-COM Technology Solutions Inc ("MACOM") products. These materials are provided by MACOM as a service to its customers and may be used for informational purposes only. Except as provided in MACOM's Terms and Conditions of Sale for such products or in any separate agreement related to this document, MACOM assumes no liability whatsoever. MACOM assumes no responsibility for errors or omissions in these materials. MACOM may make changes to specifications and product descriptions at any time, without notice. MACOM makes no commitment to update the information and shall have no responsibility whatsoever for conflicts or incompatibilities arising from future changes to its specifications and product descriptions. No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document.

THESE MATERIALS ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, EITHER EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, CONSEQUENTIAL OR INCIDENTAL DAMAGES, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT. MACOM FURTHER DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. MACOM SHALL NOT BE LIABLE FOR ANY SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS, WHICH MAY RESULT FROM THE USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.